METHYL 3,4-DIDEOXY-α-DL-threo-HEX-3-ENOPYRANOSIDE

- International Tables for X-ray Crystallography (1974). Vol. IV. Birmingham: Kynoch Press.
- JEFFREY, G. A. & ROSENSTEIN, R. D. (1964). Adv. Carbohydr. Chem. 19, 7–22.
- KONOWAL, A., JURCZAK, J. & ZAMOJSKI, A. (1968). Rocz. Chem. 42, 2045–2059.
- KRAJEWSKI, J. W., URBANCZYK-LIPKOWSKA, Z. & GLUZINSKI, P. (1978). Acta Cryst. A34, S86. In the press.
- LÓPEZ DE LERMA, J., MARTÍNEZ-CARRERA, S. & GARCÍA-BLANCO, S. (1973). Acta Cryst. B29, 537–541.
- SCHWARTZ, J. C. P. (1973). J. Chem. Soc. Chem. Commun. pp. 505-508.
- SHELDRICK, G. M. (1976). SHELX 76. Program for crystal structure determination. Univ. of Cambridge, England.
- STEWART, J. M., KUNDELL, F. A. & BALDWIN, J. C. (1970). The XRAY 70 system. Computer Science Center, Univ. of Maryland, College Park, Maryland.
- STOKHUYZEN, R. & CHUNG CHIEH (1976). J. Chem. Soc. Perkin Trans. 2, pp. 481-483.

Acta Cryst. (1979). B35, 522-524

Octaphenylcyclotetrasiloxane: The Monoclinic Form

By M. A. Hossain, M. B. Hursthouse and K. M. A. Malik

Department of Chemistry, Queen Mary College, Mile End Road, London E1 4NS, England

(Received 31 October 1978; accepted 21 November 1978)

Abstract. $C_{48}H_{40}O_4Si_4$, $M_r = 792.34$, a = 21.962 (2), b = 10.139 (1), c = 21.722 (1) Å, $\beta = 115.99$ (1)°, U = 4347.5 Å³, $D_m = 1.20$, $D_c = 1.21$ Mg m⁻³, Z = 4, space group $P2_1/c$, F(000) = 1664, $\lambda(Cu \ K\alpha) = 1.5418$ Å, $\mu(Cu \ K\alpha) = 1.502$ mm⁻¹. The structure was refined to R = 0.0711 for 4009 unique reflections. The Si₄O₄ ring is unusually flat.

Introduction. Previous work has shown that octaphenylcyclotetrasiloxane is polymorphic, occurring in monoclinic and triclinic forms and also as a benzene solvate (Hyde, Frevel, Nutting, Petrie & Purcell, 1947). As part of an investigation of the structure and conformation of cyclosiloxanes and related species, we have begun a crystallographic study of this system. Here we report the analysis of the monoclinic form.

The compound was prepared by the condensation of phenylsilanediol in alkaline medium and recrystallized from benzene-95% ethanol to obtain colourless needles. The cell parameters were initially determined from photographs and subsequently refined on a Nonius CAD-4 diffractometer from the setting angles for 25 reflections. The intensities of 7191 reflections ($3 < \theta < 60^\circ$) were recorded on the diffractometer with Ni-filtered Cu K_{α} radiation, an ω -2 θ scan technique and a crystal 0.40 × 0.15 × 0.12 mm. Two reference reflections, measured periodically, showed only minor fluctuations. The intensities were corrected for Lp factors but not for absorption. 4009 unique reflections with $F_o > 3\sigma(F_o)$ were considered observed and used in the analysis.

The structure was determined by direct methods and refined by a full-matrix least-squares procedure to a

0567-7408/79/020522-03\$01.00

final R of 0.0711. All non-hydrogen atoms were treated anisotropically. The H atoms were inserted in calculated positions (C-H = 1.08 Å) but individual $U_{\rm iso}$ values were refined. The weighting scheme was $w = 1/[\sigma^2(F_o) + 0.0004F_o^2]$, which gave flat analysis of $w\Delta^2$ with $\sin \theta$ and $[F_o/F_{\rm max}]^{1/2}$. The final non-hydrogen atomic coordinates are given in Table 1, selected interatomic distances and angles in Table 2, and leastsquares plane data in Table 3.* Neutral-atom scattering factors were taken from Stewart, Davidson & Simpson (1965) for H and from Cromer & Mann (1968) for Si. O and C.

Discussion. The molecular structure is illustrated in Fig. 1, which also shows the atom numbering. The Si–O and Si–C lengths are in good agreement with values found in other cyclotetrasiloxanes (Steinfink, Post & Fankuchen, 1955; Shklover, Kalinin, Gusev, Bokii, Struchkov, Andrianov & Petrova, 1973; Carlström & Falkenberg, 1973; Söderholm & Carlström, 1977; Söderholm, 1978). In addition the angles around Si are close to expected tetrahedral values but with the C–Si–C angles consistently a few degrees larger. An unusual feature of the structure however is the size of the Si–O–Si angles, 152 (×2) and 167° (×2). These are correlated with a much

© 1979 International Union of Crystallography

^{*} Lists of structure factors, thermal parameters, H atom positional parameters and dimensions of the phenyl rings have been deposited with the British Library Lending Division as Supplementary Publication No. SUP 34092 (24 pp.). Copies may be obtained through The Executive Secretary, International Union of Crystallography, 5 Abbey Square, Chester CH1 2HU, England.

| Table | 1. | Fractio | nal ce | oordina | ites (| $(\times 10^4)$ | of the | non- |
|-------|-----|----------|--------|-----------|---------|-----------------|--------|------|
| | hya | lrogen a | toms v | vith e.s. | .d.'s i | n paren | theses | |

у

4298(1)

5180(1)

6227(1)

5108(1)

4627(3)

4539 (3)

5788 (3)

5797(3)

2524 (4)

2036 (5)

698 (6)

269 (5)

1605 (5)

5427(4)

5869 (5)

6714 (5)

7121 (6)

6714(6)

5862 (5)

6518(5)

6298 (6)

7307 (8)

8523 (8)

8762 (7)

7765 (6)

3893 (4)

2583 (5)

1649 (6)

2044 (8)

3326 (8)

4233 (6)

8045 (4)

8669 (6)

10064 (7)

10774 (7)

10183 (6)

8818(5)

5408 (4)

4300 (5)

3722 (6)

4251 (7)

5322(7)

5900 (5)

3658 (4)

3499 (5)

2435 (7)

1537 (7)

1649 (6)

2709 (6)

6353 (5)

6276 (6)

7277 (8)

8343 (8)

8440(7)

7453 (5)

-192 (5)

z

3357(1)

2002(1)

2901(1)

4234 (1)

3870(1)

2574 (1)

2376 (1)

3669(1)

3449 (2) 3575 (2)

3619 (3)

3534 (3)

3404 (3)

3368 (3)

3572(2)

4239 (2)

4406 (3)

3912 (4)

3252 (3)

3082 (3)

1539(2)

913 (3)

586 (3)

872 (4)

1489 (5) 1816 (4)

1400(2)

1447 (3)

979 (4)

473 (3)

417 (3)

866 (2)

2875 (2)

2258 (3)

2226 (4)

2813 (5)

3433 (4)

3462 (3)

2652(2)

2231 (2)

2046 (3)

2275 (4) 2696 (4)

2883 (3)

4619(2)

4605 (3)

4926 (4)

5265 (4)

5280 (3)

4956 (3)

4886 (2)

5561 (3)

6032 (3)

5817(4)

5173 (4)

4706 (3)

х

1685(1)

1754 (1)

3267 (1)

3240(1)

2464 (1)

1556(1)

2510(1)

3434 (1)

1546 (2)

1022 (2)

926 (3)

1352 (3)

1876 (3)

1974 (2)

1142 (2)

1346 (2)

945 (3)

332 (3)

122 (3)

522 (2)

1152 (2)

603 (2)

144 (3)

235 (4)

777 (4)

1229 (3)

1751 (2)

1603 (2)

1633 (3)

1802 (3)

1944 (3)

1912 (2)

3333 (2)

3152 (3)

3202 (3)

3443 (3)

3627 (3)

3574 (3)

3877 (2)

3710 (3)

4183 (4)

4816 (4)

4996 (3)

4531 (3)

3795 (2)

4412 (2)

4833 (3)

4629 (4)

4023 (4)

3603 (3)

3338 (2)

3817 (3)

3880 (4)

3455 (5)

2989 (4)

2924 (3)

Si(1)

Si(2)

Si(3)

Si(4)

O(1)

O(2)

O(3)

O(4)

C(11)

C(12)

C(13)

C(14)

C(15)

C(16)

C(21)

C(22)

C(23)

C(24)

C(25)

C(26)

C(31)

C(32)

C(33)

C(34)

C(35)

C(36)

C(41)

C(42)

C(43)

C(44)

C(45)

C(46)

C(51)

C(52)

C(53)

C(54)

C(55)

C(56)

C(61)

C(62)

C(63)

C(64)

C(65)

C(66)

C(71) C(72)

C(73)

C(74)

C(75)

C(76)

C(81)

C(82)

C(83)

C(84)

C(85)

C(86)

 Table 2. Important bond distances (Å) and angles (°)

 with e.s.d.'s in parentheses

| Si(1) - O(1) | 1.6 | 16 (3) | Si(1) - C(1) | 1) 1· | 851 (4) |
|------------------------------|------|------------------|------------------------------|---|--------------------|
| Si(1) = O(2) Si(2) = O(2) | 1.6 | 10 (3) 21 (4) | Si(1) - C(2) Si(2) - C(3) | $\begin{array}{ccc} 1) & 1 \\ 1 \end{pmatrix} & 1 \\ \end{array}$ | 854 (5) 854 (4) |
| Si(2) = O(2) Si(2) = O(3) | 1.6 | 17(3) | Si(2) - C(4) | $1) 1 \cdot 1$ | 844 (5) |
| Si(3) - O(3) | 1.6 | 13 (3) | Si(3) - C(5) | $\vec{1}$ $\vec{1}$ | 852 (5) |
| Si(3) - O(4) | 1.60 | 04 (3) | Si(3)-C(6 | 1) 1. | 846 (6) |
| Si(4) - O(4) | 1.62 | 23 (4) | Si(4) - C(7) | 1) 1. | 857 (4) |
| Si(4) - O(1) | 1.60 | 09 (3) | Si(4)-C(8 | 1) 1. | 837 (5) |
| Mean | 1.6 | 15 | Mean | 1. | 849 |
| Si(1)-O(1)-Si(4 | 4) | 167.4 (2) | Si(2) - O(3) |)-Si(3) | 166.9 (2) |
| Si(1) - O(2) - Si(2) | 2) | 152-3 (2) | Si(3)-O(4 |)-Si(4) | 152.6 (2) |
| C(11)-Si(1)-C(| (21) | 114.7 (2) | C(51)–Si(| 3)C(61) | 111.3 (2) |
| C(11)-Si(1)-O(| (1) | 107.5 (2) | C(51)—Si(| 3)–O(3) | 108.8 (2) |
| C(11)-Si(1)-O(| (2) | 107.5 (2) | C(51)–Si(| 3)–O(4) | 108.4 (2) |
| C(21) - Si(1) - O(| (1) | 107.6 (2) | C(61)–Si(| 3)–O(3) | 108.9 (2) |
| C(21) - Si(1) - O(21) | (2) | 109.7 (2) | C(71)Si(| 3)–O(4) | 108.6 (2) |
| O(1) - Si(1) - O(2) | 2) | 109.8 (2) | O(3)-Si(3) |)—O(4) | 110.8 (2) |
| C(31)-Si(2)-C(| (41) | 110.7 (2) | C(71)–Si(| 4)-C(81) | 111.4 (2) |
| C(31)-Si(2)-O(| (2) | 109.9 (2) | C(71)–Si(| 4)–O(1) | 109.0 (2) |
| C(31)-Si(2)-O | (3) | 109.0 (2) | C(71)–Si(| 4)–O(4) | 110.1 (2) |
| C(41) - Si(2) - O(| (2) | 109.9 (2) | C(81)–Si(| 4)–O(1) | 109.1 (2) |
| C(41) Si(2)-O(| (3) | 108.1 (2) | C(81)Si(| 4)–O(4) | 107.8 (2) |
| O(2) - Si(2) - O(3) | 3) | 109.2(1) | O(1)-Si(4) |)–O(4) | 109.0 (2) |
| | | | | | |

Table 3. Least-squares planes and deviations (Å) of individual atoms

The equations of the planes are in the form Ax + By + Cz = D, where x, y, z are fractional coordinates. Asterisks indicate atoms not included in the calculation of the planes.

Plane 1: -9.5209x + 9.0508y + 6.5276z = 4.3710

| $\begin{array}{cccccccccccccccccccccccccccccccccccc$ | | | * | | | | | |
|--|---|--------|-----------------|-------|---------|--|--|--|
| $\begin{array}{cccccccccccccccccccccccccccccccccccc$ | | Si(1) | 0.1061 | O(1) | -0.0037 | | | |
| $\begin{array}{cccccccccccccccccccccccccccccccccccc$ | | Si(2) | -0.0464 | O(2) | -0.0641 | | | |
| Si(4) -0.0692 O(4) 0.0017 Plane 2: $-10.0386x + 8.9142y + 6.9703z = 4.2649$ Si(1)* 0.2148 O(1)* 0.0829 Si(2) -0.0133 O(2) 0.0133 Si(3)* 0.0276 O(3)* 0.0305 Si(4) -0.0133 O(4) 0.0132 Plane 3: $-7.4604x + 9.5162y + 4.4040z = 4.2950$ Si(1) 0.0164 O(1) -0.0264 Si(2)* 0.2070 O(2) -0.0029 Si(3)* 0.4703 O(3)* 0.3863 Si(4) 0.0129 O(4)* 0.2759 Plane 4: $-10.4423x + 8.8015y + 7.3063z = 4.1960$ Si(1)* 0.2801 Si(1)* 0.2801 O(1)* 0.1303 Si(2) -0.0062 O(2)* 0.0548 Si(3) -0.0081 O(3) 0.0128 Si(4)* 0.0096 O(4) 0.0015 | | Si(3) | 0.0473 | O(3) | 0.0283 | | | |
| Plane 2: $-10.0386x + 8.9142y + 6.9703z = 4.2649$ Si(1)* 0.2148 O(1)* 0.0829 Si(2) -0.0133 O(2) 0.0133 Si(3)* 0.0276 O(3)* 0.0305 Si(4) -0.0133 O(4) 0.0132 Plane 3: $-7.4604x + 9.5162y + 4.4040z = 4.2950$ Si(1) 0.0164 O(1) -0.0264 Si(2)* 0.2070 O(2) -0.0029 Si(3)* 0.4703 O(3)* 0.3863 Si(4) 0.0129 O(4)* 0.2759 Plane 4: $-10.4423x + 8.8015y + 7.3063z = 4.1960$ Si(1)* 0.2801 O(1)* 0.1303 Si(2) -0.0062 O(2)* 0.0548 Si(3) -0.0081 O(3) 0.0128 Si(4)* 0.0096 O(4) 0.0015 | | Si(4) | -0.0692 | O(4) | 0.0017 | | | |
| $\begin{array}{cccccccccccccccccccccccccccccccccccc$ | Plane 2: $-10.0386x + 8.9142y + 6.9703z = 4.2649$ | | | | | | | |
| $\begin{array}{cccccccccccccccccccccccccccccccccccc$ | | Si(1)* | 0.2148 | O(1)* | 0.0829 | | | |
| $\begin{array}{cccccccccccccccccccccccccccccccccccc$ | | Si(2) | -0.0133 | O(2) | 0.0133 | | | |
| $\begin{array}{c ccccccccccccccccccccccccccccccccccc$ | | Si(3)* | 0.0276 | O(3)* | 0.0305 | | | |
| Plane 3: $-7.4604x + 9.5162y + 4.4040z = 4.2950$ Si(1) 0.0164 O(1) -0.0264 Si(2)* 0.2070 O(2) -0.0029 Si(3)* 0.4703 O(3)* 0.3863 Si(4) 0.0129 O(4)* 0.2759 Plane 4: $-10.4423x + 8.8015y + 7.3063z = 4.1960$ Si(1)* 0.2801 O(1)* 0.1303 Si(2) -0.0062 O(2)* 0.0548 Si(3) -0.0081 O(3) 0.0128 Si(4)* 0.0096 O(4) 0.0015 Analysis batwan normals to planes (°) | | Si(4) | -0.0133 | O(4) | 0.0132 | | | |
| $\begin{array}{cccccccccccccccccccccccccccccccccccc$ | Plane 3: $-7.4604x + 9.5162y + 4.4040z = 4.2950$ | | | | | | | |
| $\begin{array}{cccccccccccccccccccccccccccccccccccc$ | | Si(1) | 0.0164 | O(1) | -0.0264 | | | |
| $\begin{array}{cccccccc} Si(3)^{*} & 0.4703 & O(3)^{*} & 0.3863 \\ Si(4) & 0.0129 & O(4)^{*} & 0.2759 \end{array}$ Plane 4: $-10.4423x + 8.8015y + 7.3063z = 4.1960$ Si(1)* $0.2801 & O(1)^{*} & 0.1303$ Si(2) $-0.0062 & O(2)^{*} & 0.0548$ Si(3) $-0.0081 & O(3) & 0.0128$ Si(4)* $0.0096 & O(4) & 0.0015 \end{array}$ | | Si(2)* | 0.2070 | O(2) | -0.0029 | | | |
| Si(4) 0.0129 $O(4)^*$ 0.2759 Plane 4: $-10.4423x + 8.8015y + 7.3063z = 4.1960$ Si(1)* 0.2801 $O(1)^*$ 0.1303 Si(2) -0.0062 $O(2)^*$ 0.0548 Si(3) -0.0081 $O(3)$ 0.0128 Si(4)* 0.0096 $O(4)$ 0.0015 | | Si(3)* | 0.4703 | O(3)* | 0.3863 | | | |
| Plane 4: $-10.4423x + 8.8015y + 7.3063z = 4.1960$ Si(1)* 0.2801 $O(1)$ * 0.1303 Si(2) -0.0062 $O(2)$ * 0.0548 Si(3) -0.0081 $O(3)$ 0.0128 Si(4)* 0.0096 $O(4)$ 0.0015 | | Si(4) | 0.0129 | O(4)* | 0.2759 | | | |
| $\begin{array}{ccccccc} Si(1)^{*} & 0.2801 & O(1)^{*} & 0.1303 \\ Si(2) & -0.0062 & O(2)^{*} & 0.0548 \\ Si(3) & -0.0081 & O(3) & 0.0128 \\ Si(4)^{*} & 0.0096 & O(4) & 0.0015 \end{array}$ | Plane 4: $-10.4423x + 8.8015y + 7.3063z = 4.1960$ | | | | | | | |
| $\begin{array}{ccccccc} Si(2) & -0.0062 & O(2)^{*} & 0.0548 \\ Si(3) & -0.0081 & O(3) & 0.0128 \\ Si(4)^{*} & 0.0096 & O(4) & 0.0015 \end{array}$ | | Si(1)* | 0.2801 | O(1)* | 0.1303 | | | |
| $\begin{array}{ccccccc} Si(3) & -0.0081 & O(3) & 0.0128 \\ Si(4)^{*} & 0.0096 & O(4) & 0.0015 \end{array}$ | | Si(2) | -0.0062 | O(2)* | 0.0548 | | | |
| $Si(4)^*$ 0.0096 O(4) 0.0015 | | Si(3) | -0·0081 | O(3) | 0.0128 | | | |
| Angles between normals to planes $(^{\circ})$ | | Si(4)* | 0.0096 | O(4) | 0.0015 | | | |
| Angles between normals to planes () | | | | | | | | |
| Plane 2–Plane 3 8.66 | U | | Plane 2–Plane 3 | 8.6 | 6 | | | |

greater tendency to flattening of the Si_4O_4 ring than found previously. Thus in Table 3 we see that the maximum deviation of an atom from the best plane through all eight ring atoms is 0.1 Å. A variety of trial calculations showed that the ring conformation can be most conveniently described as a shallow, distorted

boat (plane 2, Table 3) with Si(2), Si(4), O(2), O(4) forming the planar base and Si(1), O(1) and Si(3), O(3) the stern and prow.

1.32

Plane 2-Plane 4





Fig. 1. The molecular structure of octaphenylcyclotetrasiloxane showing the numbering scheme.

We consider that the flattening of the ring may be due to intramolecular crowding. Although there are no unacceptably short $C \cdots C$ contacts between phenyl groups on different Si atoms the orientations of these groups result in a fairly evenly distributed set of $C_{\beta} \cdots O$ contacts, four at each O atom, lying between $3 \cdot 13 - 3 \cdot 59$ Å.

The molecular packing is shown in Fig. 2. Although there are no intermolecular $C \cdots C$ contacts <3.63 Å, the rather unsymmetrical arrangement of phenyl-ring orientations on each molecule may have been influenced by intermolecular interactions. The molecular packing although fairly loose may therefore have an indirect effect on the molecular configuration. We have commenced an investigation of the triclinic form of this compound for comparison.

We thank the University of Dacca, Bangladesh, for a research studentship (to MAH), the SRC for a Post-



Fig. 2. The molecular packing looking down [010].

doctoral Fellowship (to KMAM) and, with the Royal Society, for assistance in the purchase of the diffractometer. Computations were performed on the Queen Mary College ICL 1904S and University of London CDC 7600 computers with programs written by Dr G. M. Sheldrick (Cambridge University). The diagrams were drawn with *PLUTO* written by Dr W. D. S. Motherwell (Cambridge University).

References

- CARLSTRÖM, D. & FALKENBERG, G. (1973). Acta Chem. Scand. 27, 1203–1209.
- CROMER, D. T. & MANN, J. B. (1968). Acta Cryst. A24, 321–324.
- Hyde, J. F., Frevel, L. K., Nutting, H. S., Petrie, P. S. & Purcell, M. A. (1947). J. Am. Chem. Soc. 69, 488–492.
- SHKLOVER, V. E., KALININ, A. E., GUSEV, A. I., BOKII, N. G., STRUCHKOV, YU. T., ANDRIANOV, K. A. & PETROVA, I. M. (1973). *Zh. Strukt. Khim.* 14, 692–699.
- Söderholm, M. (1978). Acta Chem. Scand. Ser. B, 32, 171-176.
- Söderholm, M. & Carlström, D. (1977). Acta Chem. Scand. Ser. B, **31**, 193–197.
- STEINFINK, H., POST, B. & FANKUCHEN, I. (1955). Acta Cryst. 8, 420-424.
- STEWART, R. F., DAVIDSON, E. R. & SIMPSON, W. T. (1965). J. Chem. Phys. 42, 3175–3187.